

ILD205/206/207/211/213/217 DUAL PHOTOTRANSISTOR SMALL OUTLINE SURFACE MOUNT OPTOCOUPLER

FEATURES

- **Two Channel Coupler**
- **Industry Standard SOIC-8 Surface Mountable Package**
- **Standard Lead Spacing of .05"**
- **Available in Tape and Reel Option (Conforms to EIA Standard 481-2)**
- **Isolation Test Voltage, 2500 VRMS**
- **High Current Transfer Ratios**
ILD205, 40 – 80%
ILD206, 63 – 125%
ILD207, 100 – 200%
ILD211, 20% Minimum
ILD213, 100% Minimum
ILD217, 100% Minimum at 1 mA
- **High BV_{CEO}, 70 V**
- **Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering**

DESCRIPTION

The ILD205/206/207/211/213/217 are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205/6/7/11/13/17 come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 volts gives a higher safety margin compared to the industry standard of 30 volts.

Maximum Ratings (Each Channel)

Emitter

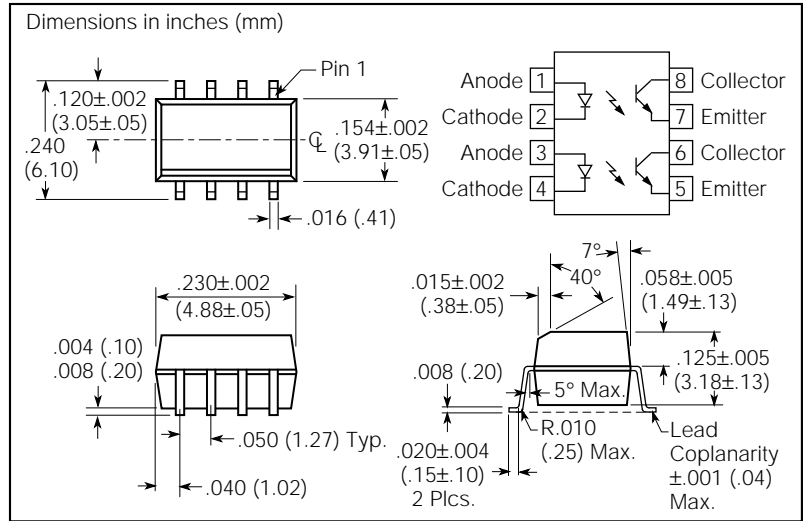
Peak Reverse Voltage 6.0 V
 Peak Pulsed Current (1 μ s, 300 pps) 1 A
 Continuous Forward Current per Channel 30 mA
 Power Dissipation at 25°C 45 mW
 Derate Linearly from 25°C 0.5 mW/°C

Detector

Collector-Emitter Breakdown Voltage 70 V
 Emitter-Collector Breakdown Voltage 7 V
 Power Dissipation per Channel 55 mW
 Derate Linearly from 25°C 0.55 mW/°C

Package

Total Package Dissipation at 25°C Ambient
 (2 LEDs + 2 Detectors, 2 Channels) 200 mW
 Derate Linearly from 25°C 2.0 mW/°C
 Storage Temperature -55°C to +150°C
 Operating Temperature -55°C to +100°C
 Soldering Time at 260°C 10 sec.



Characteristics (T_A=25°C)

Parameter	Min.	Typ	Max	Unit	Test Condition
Emitter					
Forward Voltage		1.2	1.55	V	I _F =10 mA
Reverse Current		0.1	100	mA	V _R =6.0 V
Capacitance		25		pF	V _R =0
Detector					
BV _{CEO}	70			V	I _C =10 mA
BV _{ECO}	7			V	I _E =10 mA
I _{CEO}		5	50	nA	V _{CE} =10 V I _F =0
Collector-Emitter Capacitance		10		pF	V _{CE} =0
Package					
DC Current Transfer					V _{CE} =5 V I _F =10 mA
ILD205	40		80	%	I _F =10 mA
ILD206	63		125	%	I _F =10 mA
ILD207	100		200	%	I _F =10 mA
ILD211	20			%	I _F =10 mA
ILD213	100			%	I _F =10 mA
ILD205	13	30		%	I _F =1 mA
ILD206	22	45		%	I _F =1 mA
ILD207	34	70		%	I _F =1 mA
ILD217	100	130		%	I _F =1 mA
Collector-Emitter Saturation Voltage V _{CE(sat)}			0.4	V	I _F =10 mA I _F =2.5 mA
Capacitance, Input to Output		0.5		pF	
Isolation Test Voltage	2500			VAC _{RMS}	t=1 min.
Resistance, Input to Output		100		GΩ	
Turn-on Time		5.0		μs	I _C =2 mA, R _E = 100 Ω
Turn-off Time		4.0		μs	V _{CE} =5 V

Figure 1. Forward current versus forward voltage

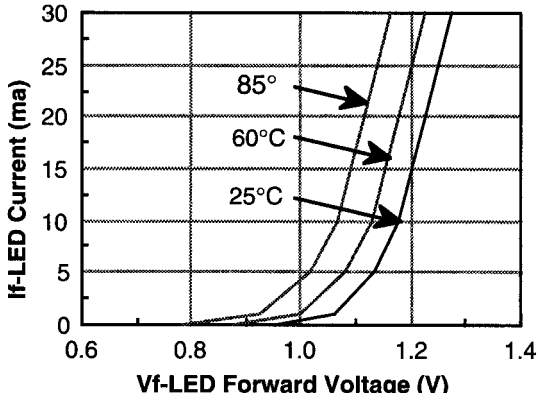


Figure 5. Switching speed versus load resistor

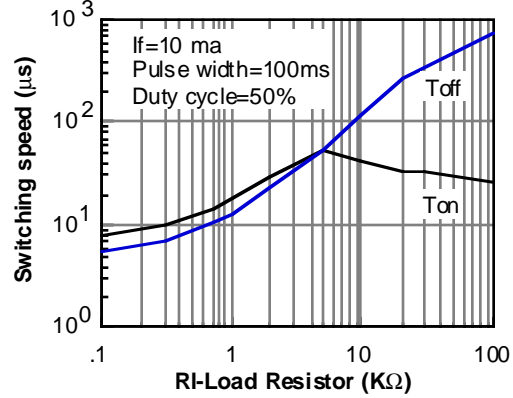


Figure 2. Collector-emitter current versus temperature

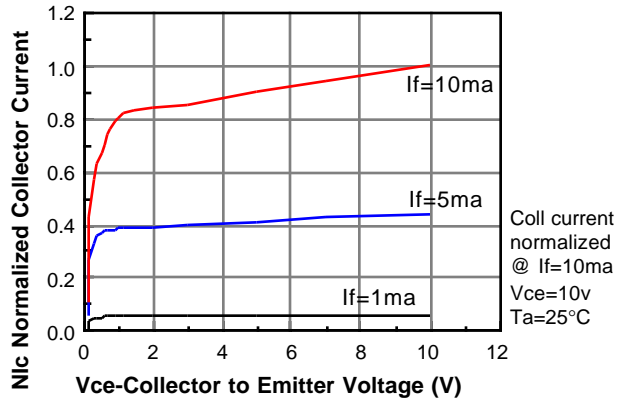


Figure 6. Collector current versus temperature

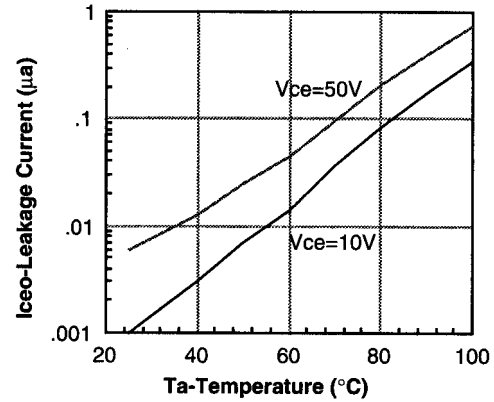


Figure 3. Normalized CTRce versus forward current

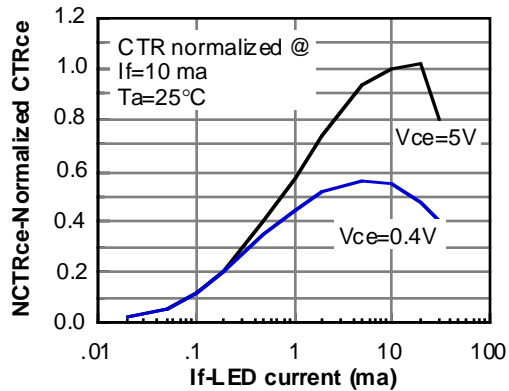


Figure 7. Power dissipation versus ambient temperature

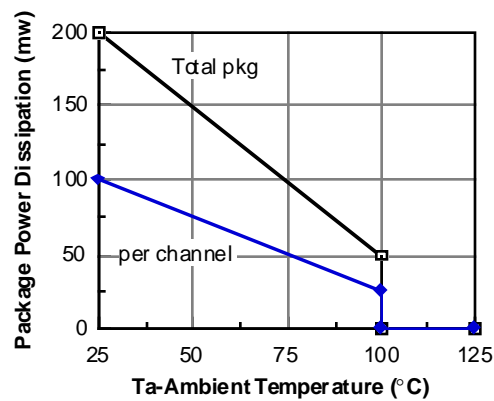


Figure 4. CTR (normalized) versus temperature

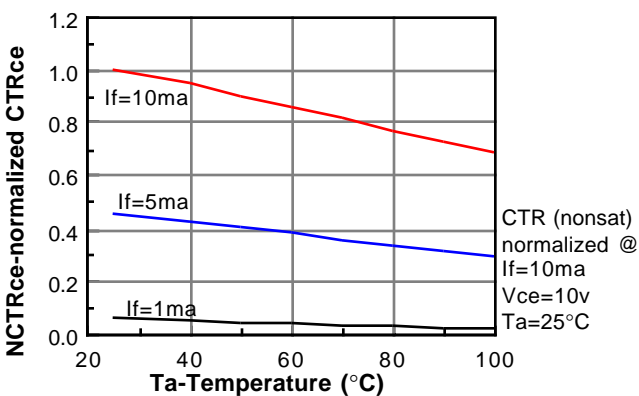


Figure 8. Switching time test schematic and waveform

